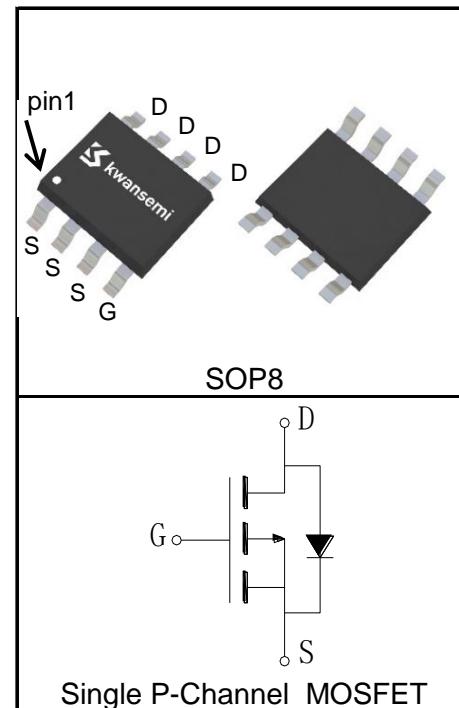


## Features

- -40V/-11A,  
 $R_{DS(ON)} = 12m\Omega$ (Typ.)@ $V_{GS}=-10V$
- $R_{DS(ON)} = 15m\Omega$ (Typ.)@ $V_{GS}=-4.5V$
- Low  $R_{DS(ON)}$
- Super High Dense Cell Design
- Reliable and Rugged

## Pin Description



## Applications

- Load Switch
- DC-DC Converter
- Power Management



Halogen-Free

## Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
<b>Common Ratings</b> ( $T_A=25^\circ C$ Unless Otherwise Noted)			
$V_{DSS}$	Drain-Source Voltage	-40	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	
$T_{Jmax}$	Maximum Junction Temperature	150	$^\circ C$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to 150	$^\circ C$
$I_S$	Diode Continuous Forward Current	$T_A=25^\circ C$	-3.1 A
<b>Mounted on Large Heat Sink</b>			
$I_{DP}^{①}$	Pulse Drain Current	$T_A=25^\circ C$	-44 A
$I_D^{②}$	Continuous Drain Current( $V_{GS}=-10V$ )	$T_A=25^\circ C$	-11 A
		$T_A=70^\circ C$	-8.7 A
$P_D$	Maximum Power Dissipation	$T_A=25^\circ C$	2.5 W
		$T_A=70^\circ C$	1.6 W
$R_{\theta JL}$	Thermal Resistance-Junction to Lead	35 $^\circ C/W$	
$R_{\theta JA}^{③}$	Thermal Resistance-Junction to Ambient	50 $^\circ C/W$	
<b>Drain-Source Avalanche Ratings</b>			
$E_{AS}^{④}$	Avalanche Energy, Single Pulsed	225 mJ	

**Electrical Characteristics** ( $T_A=25^\circ\text{C}$  Unless Otherwise Noted)

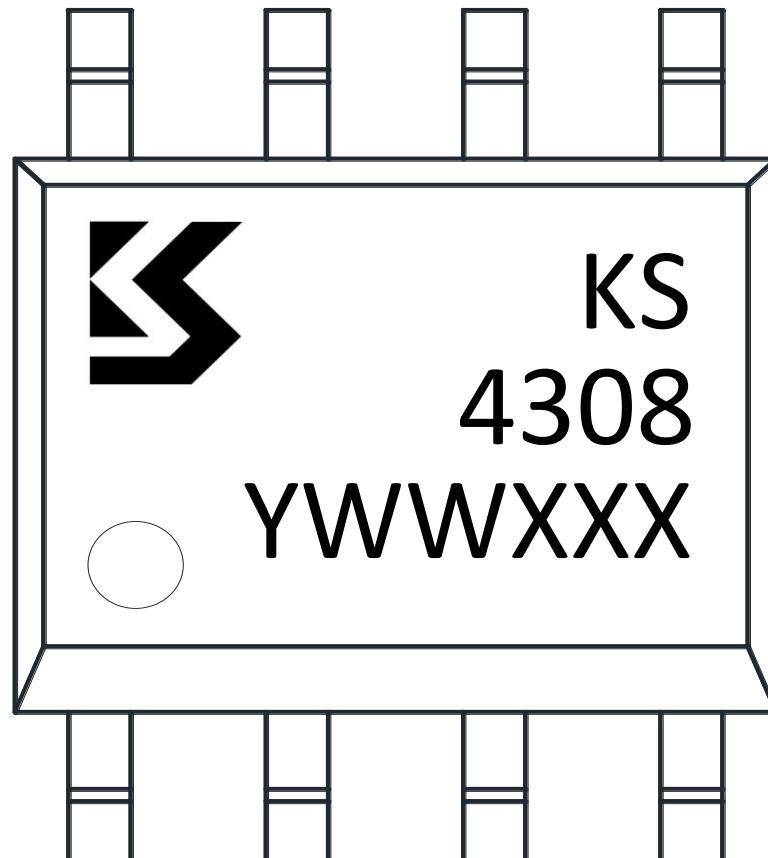
Symbol	Parameter	Test Condition	KS4308HA			Unit
			Min.	Typ.	Max.	
<b>Static Characteristics</b>						
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=-250\mu\text{A}$	-40			V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{\text{DS}}=-40\text{V}, V_{\text{GS}}=0\text{V}$			-1	$\mu\text{A}$
		$T_J=125^\circ\text{C}$			-30	
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{DS}}=-250\mu\text{A}$	-1.1	-1.5	-2.3	V
$I_{\text{GSS}}$	Gate Leakage Current	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$			$\pm 100$	nA
$R_{\text{DS}(\text{ON})}$ <sup>⑤</sup>	Drain-Source On-state Resistance	$V_{\text{GS}}=-10\text{V}, I_{\text{DS}}=-5\text{A}$		12	15	mΩ
		$V_{\text{GS}}=-4.5\text{V}, I_{\text{DS}}=-4\text{A}$		15	20	mΩ
<b>Diode Characteristics</b>						
$V_{\text{SD}}$ <sup>⑤</sup>	Diode Forward Voltage	$I_{\text{SD}}=-5\text{A}, V_{\text{GS}}=0\text{V}$		-0.79	-1.2	V
$t_{\text{rr}}$	Reverse Recovery Time	$I_{\text{SD}}=-5\text{A}, dI_{\text{SD}}/dt=-100\text{A}/\mu\text{s}$		58		ns
$Q_{\text{rr}}$	Reverse Recovery Charge			33		nC
<b>Dynamic Characteristics</b> <sup>⑥</sup>						
$R_G$	Gate Resistance	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=0\text{V}, F=1\text{MHz}$		6		Ω
$C_{\text{iss}}$	Input Capacitance	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=-20\text{V}, \text{Frequency}=1.0\text{MHz}$		3320		pF
$C_{\text{oss}}$	Output Capacitance			265		
$C_{\text{rss}}$	Reverse Transfer Capacitance			245		
$t_{\text{d}(\text{ON})}$	Turn-on Delay Time	$V_{\text{DD}}=-20\text{V}, I_{\text{DS}}=-5\text{A}, V_{\text{GEN}}=-10\text{V}, R_G=6\Omega$		19		ns
$t_r$	Turn-on Rise Time			24		
$t_{\text{d}(\text{OFF})}$	Turn-off Delay Time			53		
$t_f$	Turn-off Fall Time			19		
<b>Gate Charge Characteristics</b> <sup>⑥</sup>						
$Q_g$	Total Gate Charge	$V_{\text{DS}}=-20\text{V}, V_{\text{GS}}=-10\text{V}, I_{\text{DS}}=-5\text{A}$		50		nC
$Q_{\text{gs}}$	Gate-Source Charge			7.5		
$Q_{\text{gd}}$	Gate-Drain Charge			14		

Notes:

- ①Pulse width limited by safe operating area.
- ②Calculated continuous current based on maximum allowable junction temperature.
- ③When mounted on 1 inch square copper board,  $t \leq 10\text{sec}$ . The value in any given application depends on the user's specific board design.
- ④Limited by  $T_{J\text{max}}$ , Starting  $T_J = 25^\circ\text{C}$ ,  $I_{AS\text{max}} = -30\text{A}$ ,  $L = 0.5\text{mH}$ ,  $V_{\text{DD}} = -24\text{V}$ ,  $R_G = 25\Omega$ ,  $V_{\text{GS}} = -10\text{V}$ . Part not recommended for use above this value.
- ⑤Pulse test; Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- ⑥Guaranteed by design, not subject to production testing.

**Ordering and Marking Information**

Device	Package	Packaging	Quantity	Reel Size	Tape width
KS4308HA	SOP8	Tape&Reel	3000	13"	12mm

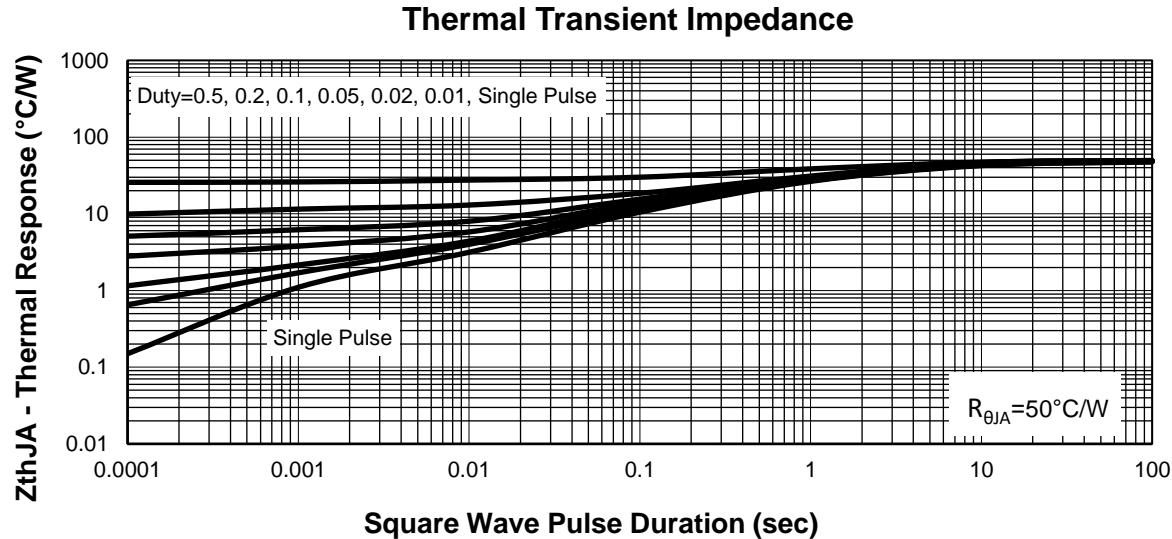
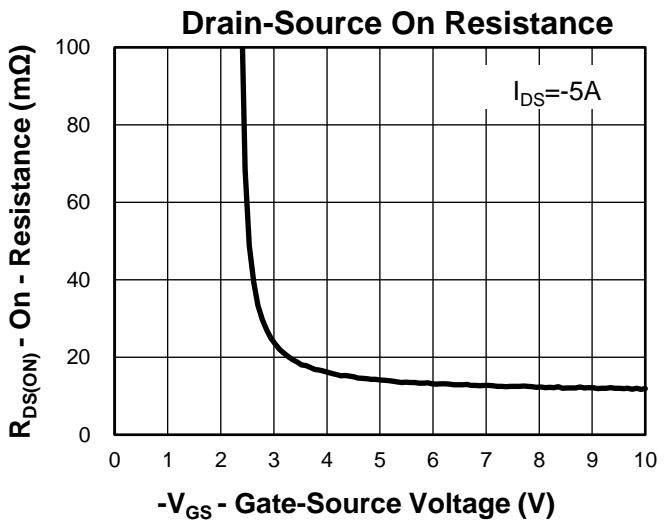
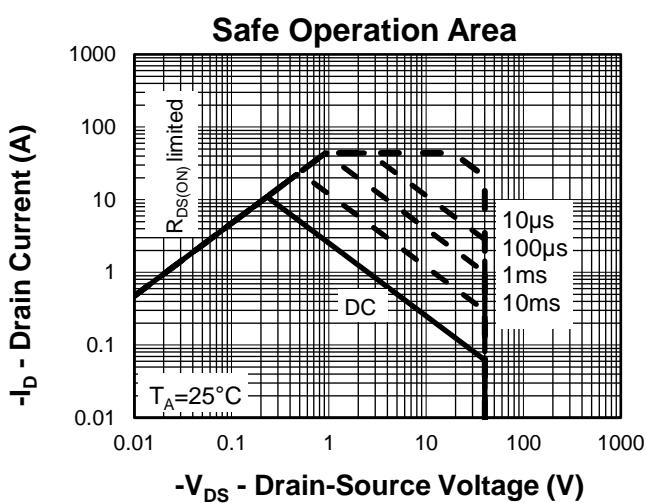
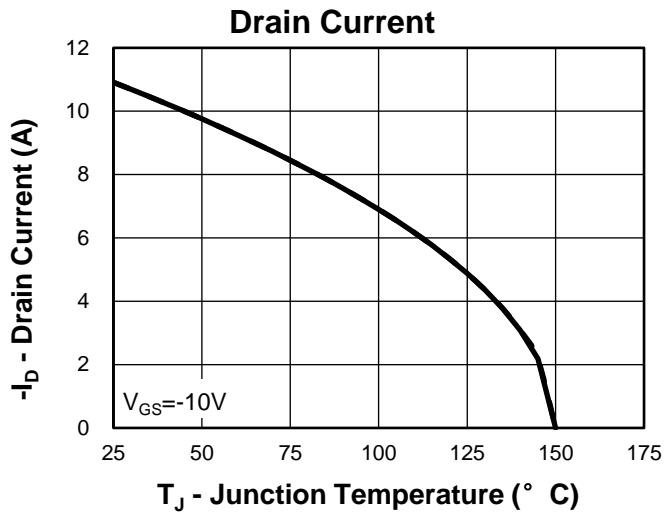
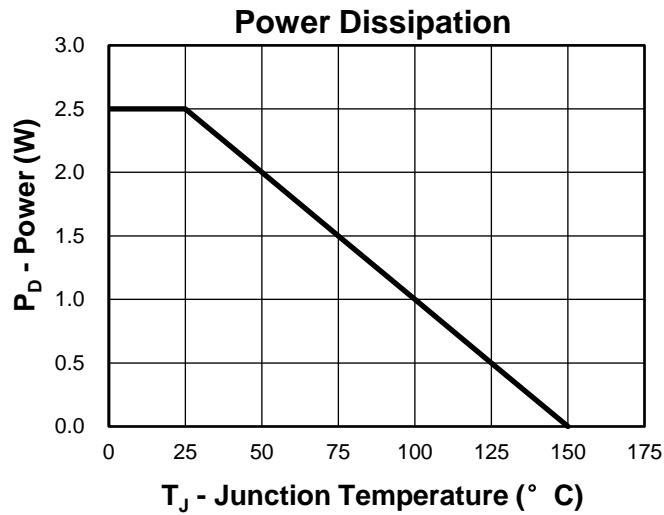


1st Line: Kwansemi LOGO, Kwansemi Code(KS)

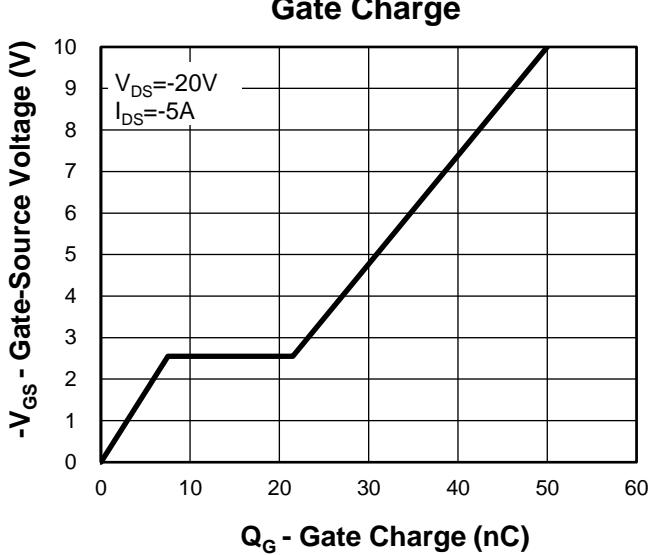
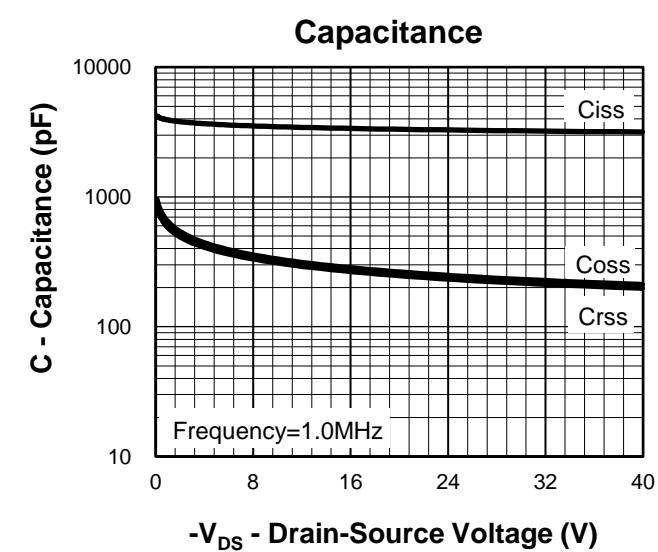
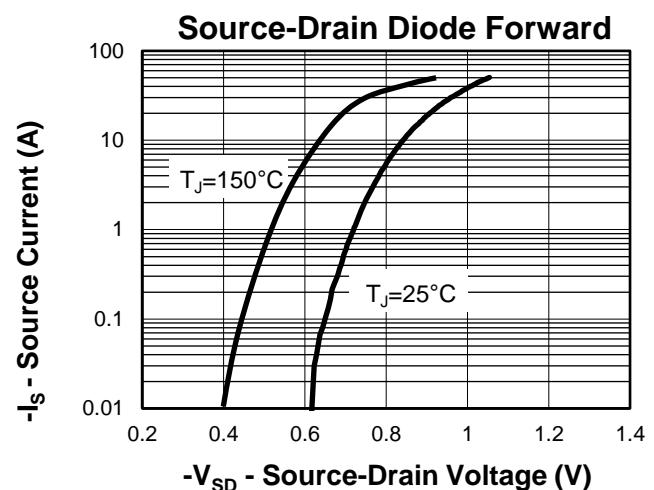
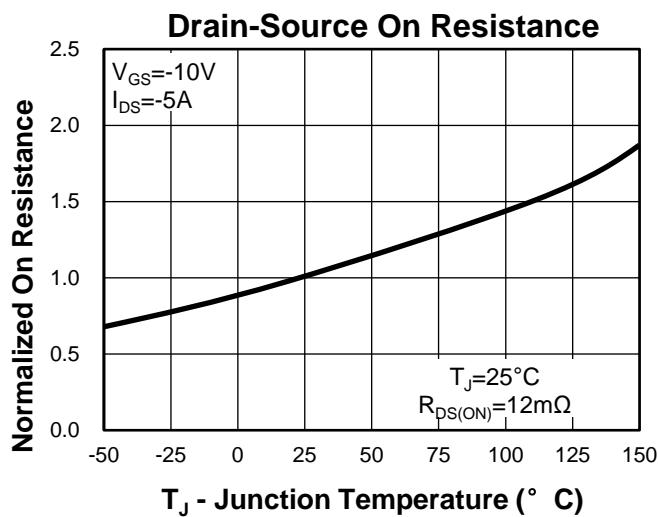
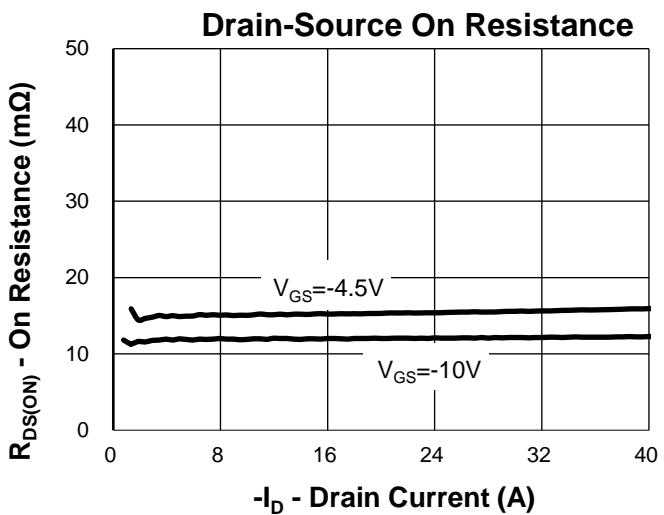
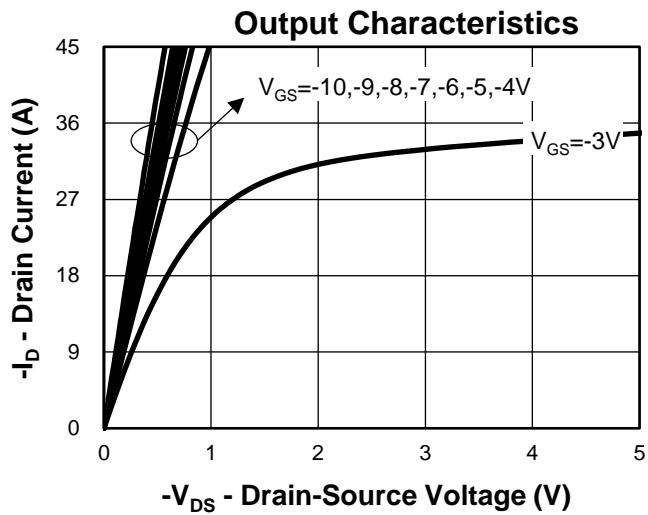
2nd Line: Part Number(4308)

3rd Line: Lot Number(YWWXXX)

## Typical Characteristics

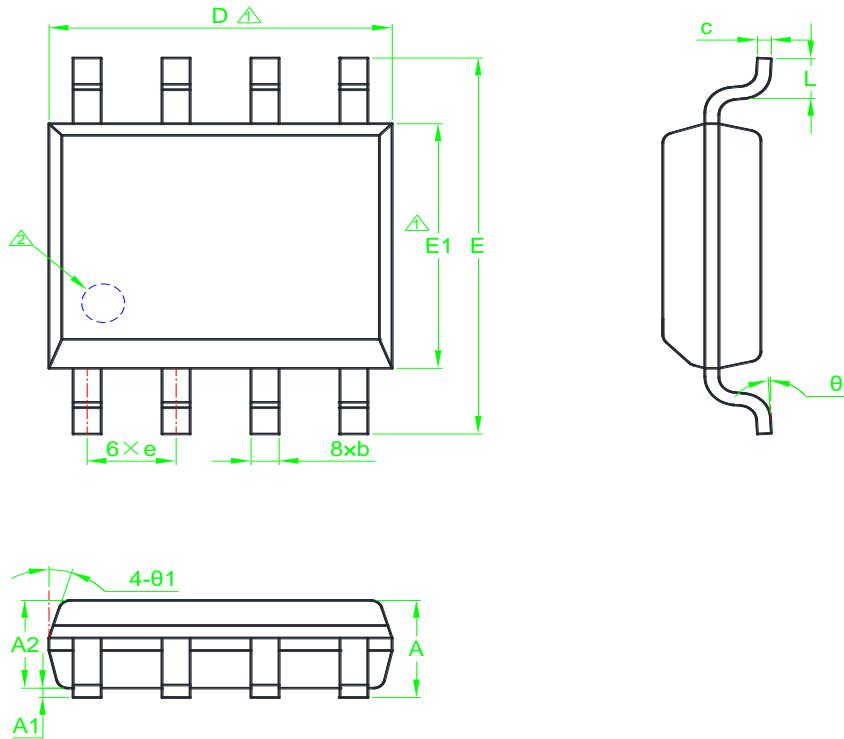


## Typical Characteristics



## Package Information

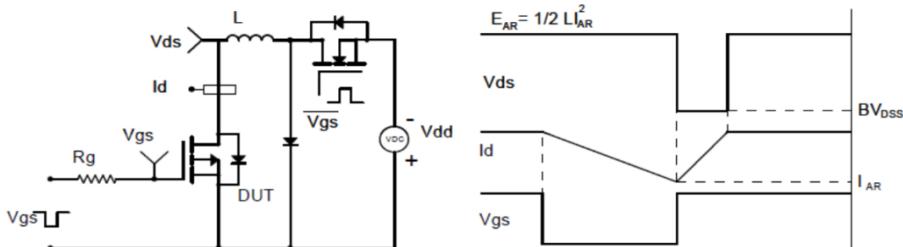
### SOP8



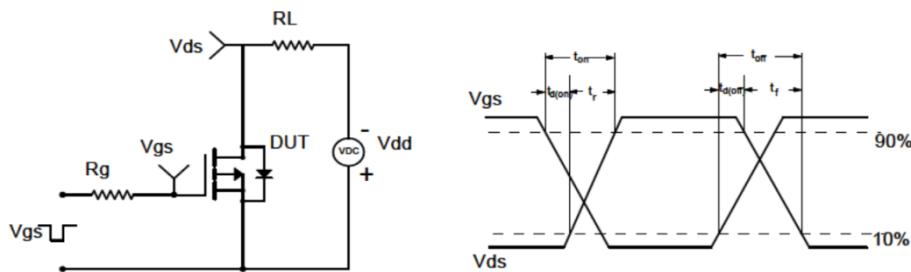
SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.35	*	1.75	0.053	*	0.069
A1	0.10	*	0.25	0.004	*	0.010
A2	1.25	1.45	1.65	0.049	0.057	0.065
b	0.33	*	0.51	0.013	*	0.020
c	0.15	*	0.25	0.006	*	0.010
D	4.70	4.90	5.10	0.185	0.193	0.201
E	5.80	6.00	6.30	0.228	0.236	0.248
E1	3.80	3.90	4.00	0.150	0.154	0.157
e	1.27BSC			0.050BSC		
L	0.40	*	1.27	0.016	*	0.050
θ	0°	*	8°	0°	*	8°
θ 1	5°	*	15°	5°	*	15°

- 1 Dimensions D and E1 do not include mold flash protrusions or gate burrs.  
 2 The existence and size of demolding hole are variable depending on mold.

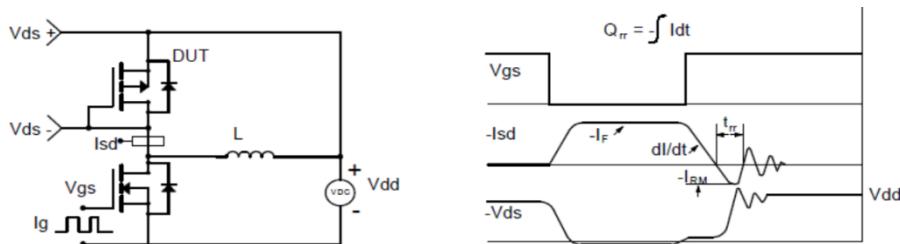
### Avalanche Test Circuit and Waveforms



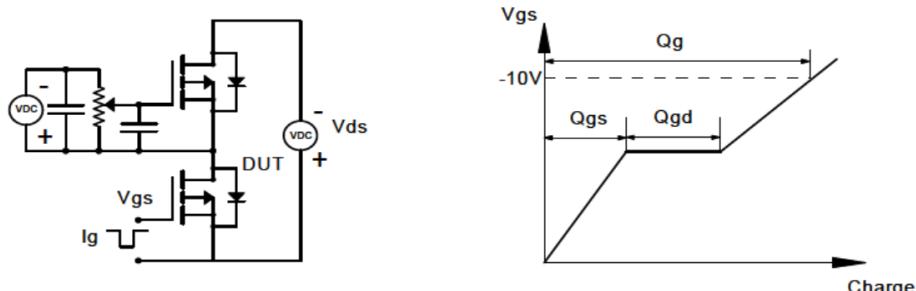
### Switching Time Test Circuit and Waveforms



### Diode Recovery Test Circuit and Waveforms



### Gate Charge Test Circuit and Waveform



### Customer Service

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Web:[www.kwansemi.com](http://www.kwansemi.com)

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